

Schottky barrier rectifier diodes

BYG90-40 series

FEATURES

- Low switching losses
- Capability of absorbing very high surge current
- Fast recovery time
- Guard ring protected
- Plastic SMD package.

APPLICATIONS

- Low power switched-mode power supplies
- Rectifying
- Polarity protection.

DESCRIPTION

The BYG 90-40 series consists of Schottky barrier rectifier diodes, fabricated in planar technology, and encapsulated in rectangular SOD106A plastic SMD packages.

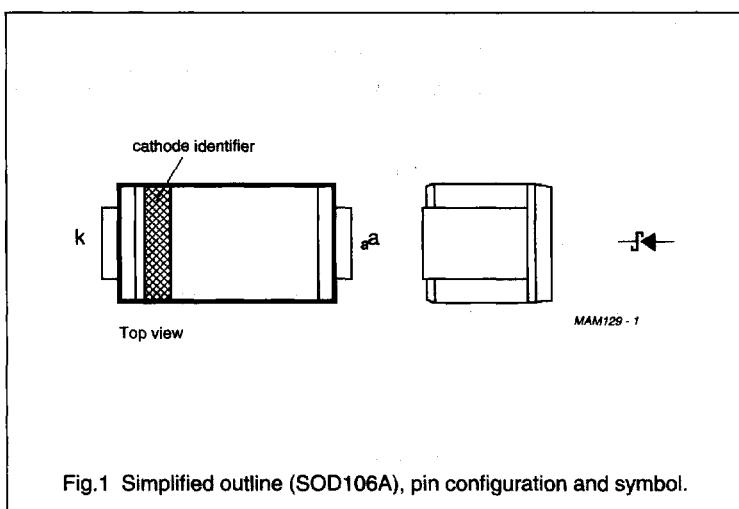


Fig.1 Simplified outline (SOD106A), pin configuration and symbol.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage BYG90-20 BYG90-30 BYG90-40		—	20	V
			—	30	V
			—	40	V
V_{RRM}	repetitive peak reverse voltage BYG90-20 BYG90-30 BYG90-40		—	20	V
			—	30	V
			—	40	V
V_{RWM}	crest working reverse voltage BYG90-20 BYG90-30 BYG90-40		—	20	V
			—	30	V
			—	40	V
$I_{F(AV)}$	average forward current	$T_{amb} = 65 \text{ }^{\circ}\text{C}$; see Fig.2; $R_{th\ j-a} = 80 \text{ K/W}$; note 1; $V_{R(equiv)} = 0.2 \text{ V}$; note 2	—	1	A
I_{FSM}	non-repetitive peak forward current	$t = 8.3 \mu\text{s}$ half sine wave; JEDEC method	—	30	A
I_{RSM}	non-repetitive peak reverse current	$t_p = 100 \mu\text{s}$	—	0.5	A
T_{sig}	storage temperature		-65	+125	$^{\circ}\text{C}$
T_j	junction temperature		—	125	$^{\circ}\text{C}$

Notes

1. Refer to SOD106A standard mounting conditions.
2. For Schottky barrier diodes thermal run-away has to be considered, as in some applications, the reverse power losses P_R are a significant part of the total power losses. Nomograms for determination of the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

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ELECTRICAL CHARACTERISTICS $T_{amb} = 25^\circ C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per diode						
V_F	forward voltage	see Fig.2; note 1 $I_F = 1 A$ $I_F = 3 A$ $I_F = 1 A; T_J = 100^\circ C$	-	-	550	mV
I_R	reverse current	$V_R = V_{RRMmax}$; note 1; see Fig.3	-	-	1	mA
		$V_R = V_{RRMmax}; T_J = 100^\circ C$; note 1; see Fig.3	-	-	10	mA
C_d	diode capacitance	$V_R = 4 V; f = 1 MHz$; see Fig.4	-	-	75	pF

Note

1. Pulsed test: $t_p = 300 \mu s$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th,j-a}$	thermal resistance from junction to ambient	note 1	80	K/W

Note

1. Refer to SOD106A standard mounting conditions.

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GRAPHICAL DATA

